# NSN 5962-01-195-2283

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-195-2283

## **Body Length:**

Between 1.190 inches and 1.290 inches

## **Body Width:**

0.610 inches

## **Body Height:**

Between 0.090 inches and 0.170 inches

## **Maximum Power Dissipation Rating:**

0.83 watts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Monolithic and bipolar and programmed

### **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

14 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

### **Memory Capacity:**

Unknown

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

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